

# **BCW33LT3G Datasheet**

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DiGi Electronics Part Number	BCW33LT3G-DG
Manufacturer	onsemi
Ianufacturer Product Number	BCW33LT3G
Description	TRANS NPN 32V 0.1A SOT23-3
Detailed Description	Bipolar (BJT) Transistor NPN 32 V 100 mA 300 mW S urface Mount SOT-23-3 (TO-236)

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BCW33LT3G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
32 V	250mV @ 500μA, 10mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	420 @ 2mA, 5V
Power - Max:	Frequency - Transition:
300 mW	
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3 (TO-236)
Base Product Number:	
BCW33	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

# **General Purpose Transistor**

## **NPN Silicon**

#### Features

• Pb–Free Packages are Available

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	32	Vdc
Collector – Base Voltage	V <sub>CBO</sub>	32	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit		
Total Device Dissipation FR–5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	PD	225 1.8	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W		
Total Device Dissipation Alumina Substrate (Note 2), $T_A = 25^{\circ}C$ Derate above 25°C	PD	300 2.4	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	417	°C/W		
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C		

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

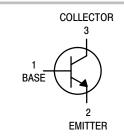
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

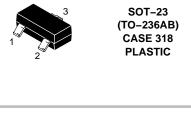
2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



### **ON Semiconductor®**

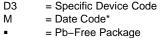
#### http://onsemi.com





#### MARKING DIAGRAM





(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BCW33LT1	SOT-23	3000/Tape & Reel
BCW33LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
BCW33LT3	SOT-23	10,000/Tape & Reel
BCW33LT3G	SOT–23 (Pb–Free)	10,000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### BCW33LT3G onsemi TRANS NPN 32V 0.1A SOT23-3

## BCW33LT1

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS		•	•	
Collector – Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	32	-	Vdc
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_B = 0)$	V <sub>(BR)CBO</sub>	32	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \ \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = 32 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 32 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	Ісво	_ _	100 10	nAdc μAdc
ON CHARACTERISTICS				
DC Current Gain ( $I_C = 2.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ )	hFE	420	800	-
Collector – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	-	0.25	Vdc
Base – Emitter On Voltage ( $I_C = 2.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ )	V <sub>BE(on)</sub>	0.55	0.70	Vdc
SMALL-SIGNAL CHARACTERISTICS		•	•	•
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )	C <sub>obo</sub>	-	4.0	pF
Noise Figure (V <sub>CE</sub> = 5.0 Vdc, I <sub>C</sub> = 0.2 mAdc, R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	NF	-	10	dB

#### **EQUIVALENT SWITCHING TIME TEST CIRCUITS**

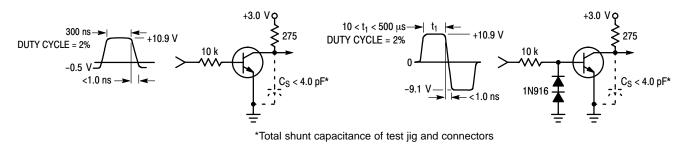
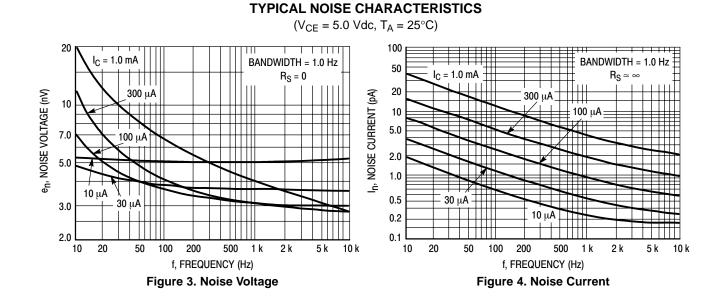
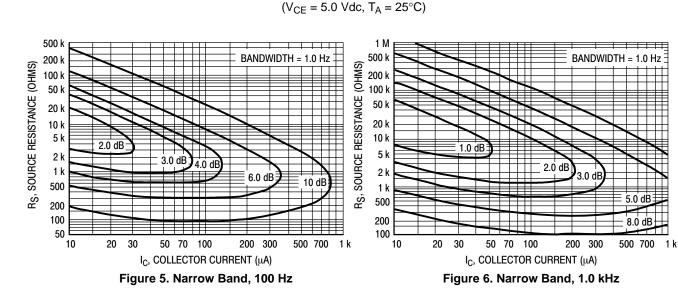


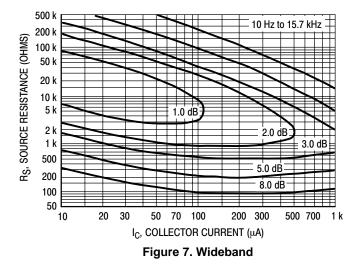
Figure 1. Turn–On Time

Figure 2. Turn-Off Time



**NOISE FIGURE CONTOURS** 





Noise Figure is defined as:

$$NF = 20 \log_{10} \left( \frac{e_{n}^{2} + 4KTR_{S} + I_{n}^{2}R_{S}^{2}}{4KTR_{S}} \right)^{1/2}$$

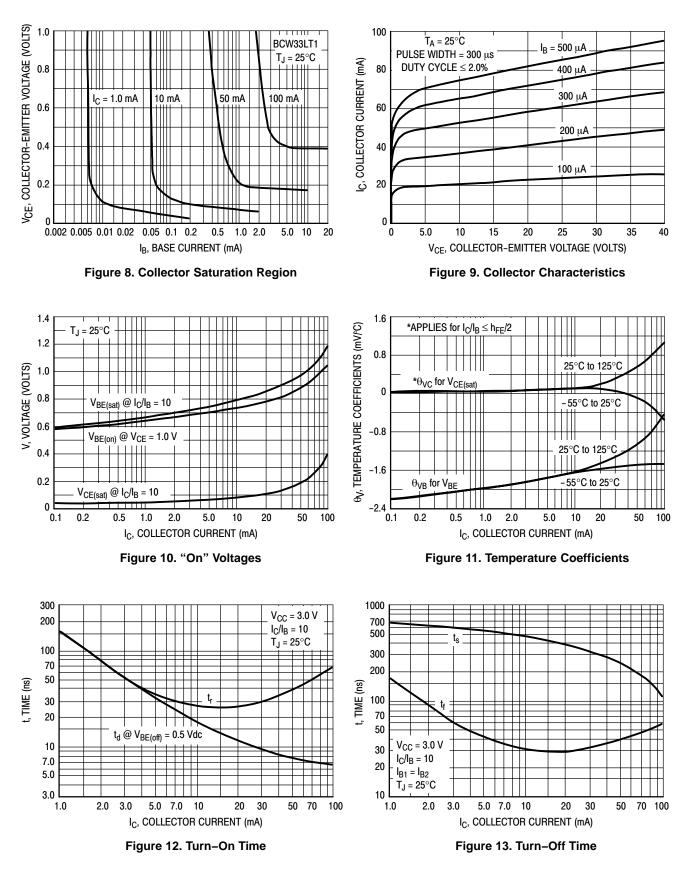
en = Noise Voltage of the Transistor referred to the input. (Figure 3)

 $I_n$  = Noise Current of the Transistor referred to the input. (Figure 4)

K = Boltzman's Constant (1.38 x 10<sup>-23</sup> j/°K)

- T = Temperature of the Source Resistance ( $^{\circ}$ K)
- R<sub>S</sub> = Source Resistance (Ohms)

#### **TYPICAL STATIC CHARACTERISTICS**



#### **TYPICAL DYNAMIC CHARACTERISTICS**

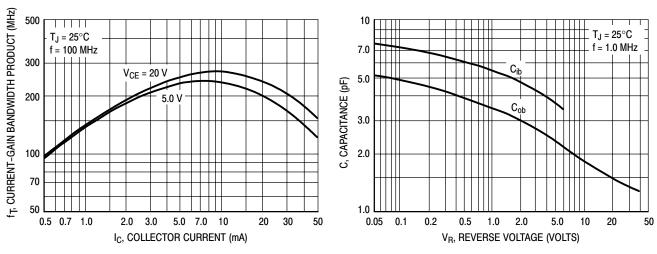




Figure 15. Capacitance

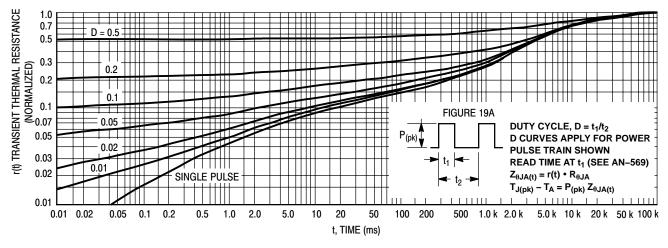


Figure 16. Thermal Response

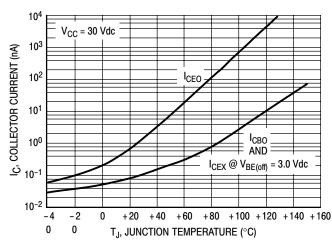


Figure 16A.

#### DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 16A. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 16 was calculated for various duty cycles.

To find  $Z_{\theta JA(t)},$  multiply the value obtained from Figure 16 by the steady state value  $R_{\theta JA}.$ 

Example:

The MPS3904 is dissipating 2.0 watts peak under the following conditions:

 $t_1 = 1.0 \text{ ms}, t_2 = 5.0 \text{ ms}. (D = 0.2)$ 

Using Figure 16 at a pulse width of 1.0 ms and D = 0.2, the reading of r(t) is 0.22.

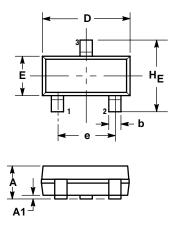
The peak rise in junction temperature is therefore

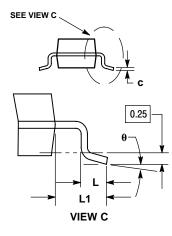
 $\Delta T = r(t) \times P_{(pk)} \times R_{\theta JA} = 0.22 \times 2.0 \times 200 = 88^{\circ}C.$ 

For more information, see AN–569.

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- TI4-300, 1902. CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF 3.
- BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE. NEW 4 STANDARD 318-08

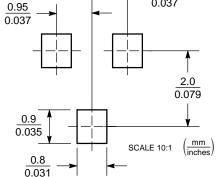
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

PIN 1. BASE 2. EMITT EMITTER

3. COLLECTOR

**SOLDERING FOOTPRINT\*** 0.95 0.037



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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